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Substitute for form 1449A/PTO (modified) **INFORMATION DISCLOSURE STATEMENT BY APPLICANT** (use as many sheets as necessary)				***Complete if known***	
				Application Number	**Not yet assigned**
				Filing Date	**Concurrently Herewith**
				First Named Inventor	**Selena Chan**
				Group Art Unit	Not yet assigned
				Examiner Name	Not yet assigned
Sheet	1	of	4	Attorney Docket	42P14246X

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No.[1]	U.S. Patent Document Number	Kind Code[2] (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines Where Relevant Passages or Figures Appear
K.G.		5,306,403		Vo-Dinh	04/26/1994	
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Examiner Signature	Karen Geisel	Date Considered	7/04

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				Examiner Name	Not yet assigned
Sheet	2	of	4	Attorney Docket Number	42P14246X

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	T[2]
K.G.		Schoenfeld, et al., "Formation of Si Quantum Dots in Nanocrystalline Silicon," Proc. 7th Int. Conf. On Modulated Semiconductor Structures, Madrid, pp. 605-608, 1995.	

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K.G.		5,255,067		Carrabba, et al.	10-19-1993	
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Examiner Signature	Kara Geisel	Date Considered	7/04

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K.G.		CAI, et al., "Optical Properties of Ag and Au Nanoparticles Dispersed within the Pores of Monolithic Mesoporous Silica," *J. Nanoparticle Res.* 3:443-453, 2001.	
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K.G.		WEIPING, et al. "Synthesis and Structural and Optical Properties of Mesoporous Silica Containing Silver Nanoparticles," *J. Phys. Condens. Matter* 9:7257-67, 1997.	

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